## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Havemann et al.

Examiner:

**TBD** 

Serial No:

**TBD** 

Art Unit:

**TBD** 

Filed:

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Docket No.: TI-27506

For:

INTEGRATED CIRCUIT HAVING A DOPED POROUS DIELECTRIC AND

METHOD OF MANUFACTURING THE SAME

## INFORMATION DISCLOSURE STATEMENT

November 1, 2001

Assistant Commissioner for Patents Washington, DC 20231

Dear Sir:

Please make the references listed on the enclosed PTO-1449 of record under 37 C.F.R. 1.56, 1.97, and 1.98 in the patent application identified above. Copies of the listed references are enclosed.

Respectfully submitted,

lacqueline J. Garner Attorney for Applicants Reg. No. 36,144

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